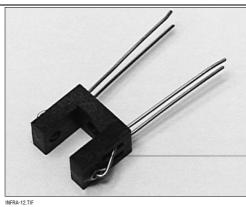
### **Transmissive Sensor**

#### **FEATURES**

- Choice of phototransistor or photodarlington output
- Low profile package
- Wide operating temperature range (- 55°C to +100°C)
- 0.200 in.(5.08 mm) slot width



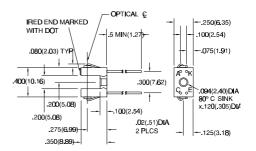
#### DESCRIPTION

The HOA1875 series consists of an infrared emitting diode facing an NPN silicon phototransistor (HOA1875-001, -002) or photodarlington (HOA1875-003) encased in a black thermoplastic housing. Detector switching takes place whenever an opaque object passes through the slot between emitter and detector. The HOA1875 series has a 0.050 in.(1.27 mm) dia. detector aperture and employs metal can packaged components. For additional component information see SE1450, SD1440, and SD1410.

Housing material is opaque polysulfone. Housings are soluble in chlorinated hydrocarbons and ketones. Recommended cleaning agents are methanol and isopropanol.

### OUTLINE DIMENSIONS in inches (mm)

3 plc decimals ±0.010(0.25) 2 plc decimals ±0.020(0.51)



DIM\_047.cdr



### **Transmissive Sensor**

#### ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
IR EMITTER						
Forward Voltage	VF			1.6	V	I <sub>F</sub> =20 mA
Reverse Leakage Current	I <sub>R</sub>			10	μΑ	V <sub>R</sub> =3 V
DETECTOR Collector-Emitter Breakdown Voltage HOA1875-001, -002 HOA1875-003	V <sub>(BR)</sub> ceo	30 15			V	Ic=100 μA
Emitter-Collector Breakdown Voltage	V <sub>(BR)ECO</sub>	5.0			V	I <sub>E</sub> =100 μA
Collector Dark Current HOA1875-001, -002 HOA1875-003	Iceo			100 250	nA	V <sub>CE</sub> =10 V I <sub>F</sub> =0
COUPLED CHARACTERISTICS On-State Collector Current HOA1875-001 HOA1875-002 HOA1875-003	Ic(on)	0.15 0.6 1.8			mA	V <sub>CE</sub> =5 V I <sub>F</sub> =30 mA
Collector-Emitter Saturation Voltage HOA1875-001 HOA1875-002 HOA1875-003	VCE(SAT)			0.4 0.4 1.1	V	I <sub>F</sub> =20 mA I <sub>C</sub> =20 μA I <sub>C</sub> =80 μA I <sub>C</sub> =230 μA
Rise And Fall Time HOA1875-001, -002 HOA1875-003	t <sub>r</sub> , t <sub>f</sub>		15 75		μs	Vcc=5 V, lc=1 mA $R_L$ =1000 $\Omega$ $R_L$ =100 $\Omega$

#### **ABSOLUTE MAXIMUM RATINGS**

(25°C Free-Air Temperature unless otherwise noted)

Operating Temperature Range -55°C to 100°C

Storage Temperature Range -55°C to 125°C

Soldering Temperature (10 sec) 260°C

soldering Temperature (10 sec) 260°C

IR EMITTER

Power Dissipation 75 mW <sup>(1)</sup>
Reverse Voltage 3 V
Continuous Forward Current 50 mA

 DETECTOR
 TRANS.
 DARLINGTON

 Collector-Emitter Voltage
 30 V
 15 V

 Emitter-Collector Voltage
 5 V
 5 V

 Power Dissipation
 75 mW (1)
 75 mW (1)

30 mA

30 mA

TRANSISTOR DARLINGTON

Anode Collector Anode Collector

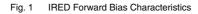
Cathode Emitter Cathode Emitter

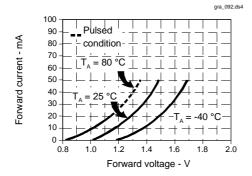
Honeywell reserves the right to make changes in order to improve design and supply the best products possible.

Collector DC Current

Honeywell

### **Transmissive Sensor**





100

1000

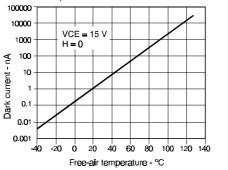
Load resistance - Ohms

10000

10

gra\_303.cdr

Fig. 3 Dark Current vs
Temperature



Collector Current vs Fig. 4 **Ambient Temperature** gra\_095.ds4 Normalized collector current 1.0 0.4 0.2 0.0 75 -50 0 25 50 100 Free-air temperature - °C

All Performance Curves Show Typical Values

**Transmissive Sensor**